

63SPD100A

Technical Data Data Sheet N1994, Rev. -



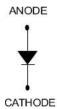
# Power Surface Mount Schottky Rectifier (100V, 60Amp)



#### Features

- 175 °C T<sub>J</sub> operation
- Low forward voltage drop
- High surge capacities
- High frequency operation
- Guaranteed reverse avalanche capability
- Low profile surface mount package
- Baseplate: Pure Sn plated; Terminals: Pure Sn plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Schematic & Pin Configuration**



# Applications

- Switching power supply
- Redundant power subsystems
- Reverse battery protection
- Converters
- Many other high current AC/DC power supplies

#### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	100	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc =116°C, rectangular wave form	60	A
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	860	A
Non-Repetitive Avalanche Energy	E <sub>AS</sub>	TJ=25℃,I <sub>AS</sub> =0.75A, L=40 mH	11.25	mJ
Repetitive Avalanche Current	lar	$I_{AS}$ decaying linearly to 0 in 1 $\mu$ sec Frequency limited by T_J max. V_A=1.5 $\timesV_R$	0.75	A

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#### **Electrical Characteristics:**

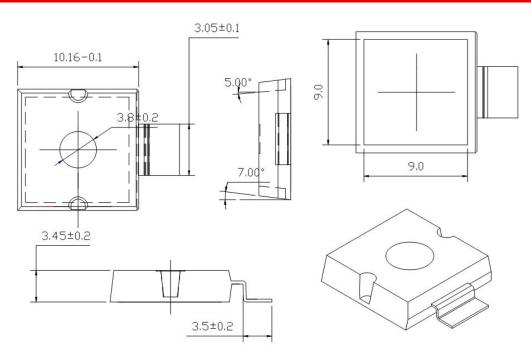
Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop *	V <sub>F1</sub>	@ 60A, Pulse, T <sub>J</sub> = 25 °C	0.79	0.87	V
	V <sub>F2</sub>	@ 60A, Pulse, T <sub>J</sub> = 125 °C	0.65	0.72	V
Reverse Current*	I <sub>R1</sub>	$@V_R = rated V_R, Pulse, T_J = 25 °C$	0.001	1.0	mA
	I <sub>R2</sub>	$@V_R = rated V_R, Pulse, T_J = 125 °C$	0.6	24.0	mA
Junction Capacitance	Ст	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C f <sub>SIG</sub> = 1MHz	1200	1500	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

\* Pulse width < 300 µs, duty cycle < 2%

### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	0.37	°C/W
Approximate Weight	wt	-	1.1	g

### Mechanical Dimensions Mini SPD-4(Millimeters)



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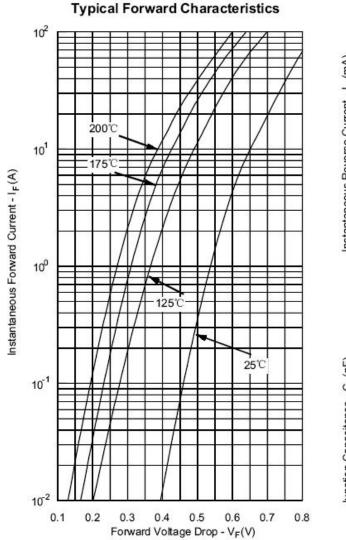
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#### **Ratings and Characteristics Curves**

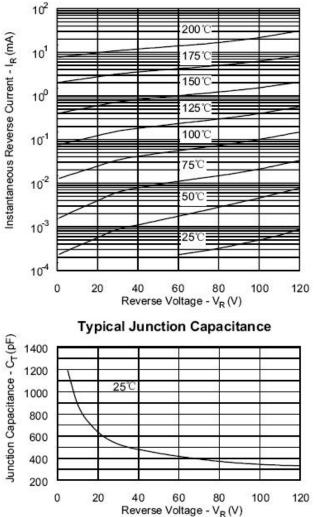


### **Ordering Information**

Device	Package	Plating	Shipping
63SPD100A	Mini SPD-4 (Pb-Free)	Pure Sn	64pcs/bag

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

**Typical Reverse Characteristics** 



#### **Marking Diagram**



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